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19-4705; Rev 4; 6/04



Improved, Quad, SPST Analog Switches

General Description

Maxim's redesigned DG444/DG445 analog switches now feature on-resistance matching (4 Ω max) between switches and guaranteed on-resistance flatness over the signal range (9 Ω max). These low on-resistance switches conduct equally well in either direction. They guarantee low charge injection (10pC max), low power consumption (35µW max), and an electrostatic discharge (ESD) tolerance of 2000V (min) per Method 3015.7. The new design offers lower off-leakage current over temperature (less than 5nA at +85°C).

The DG444/DG445 are quad, single-pole/single-throw (SPST) analog switches. The DG444 has four normally closed switches and the DG445 has four normally open switches. Switching times are less than 250ns for ton and less than 70ns for toff. Operation is from a single +10V to +30V supply, or bipolar ±4.5V to ±20V supplies. Maxim's improved DG444/DG445 continue to be fabricated with a 44V silicon-gate process.

Applications

Sample-and-Hold Circuits
Test Equipment
Heads-Up Displays
Guidance and Control
Systems
Military Radios

Communication Systems
Battery-Operated Systems
PBX, PABX
Audio Signal Routing
Modems/Faxes

_New Features

- ♦ Plug-In Upgrades for Industry-Standard DG444/DG445
- ♦ Improved Ron Match Between Channels (4Ω max)
- ♦ Guaranteed RFLAT(ON) Over Signal Range (9Ω max)
- ♦ Improved Charge Injection (10pC max)
- Improved Off-Leakage Current Over Temperature (< 5nA at +85°C)
- ♦ Withstand ESD (2000V min) per Method 3015.7

Existing Features

- ♦ Low RDS(ON) (85 Ω max)
- ♦ Single-Supply Operation +10V to +30V Bipolar-Supply Operation ±4.5V to ±20V
- ♦ Low Power Consumption (35µW max)
- ♦ Rail-to-Rail Signal Handling
- ♦ TTL/CMOS-Logic Compatible

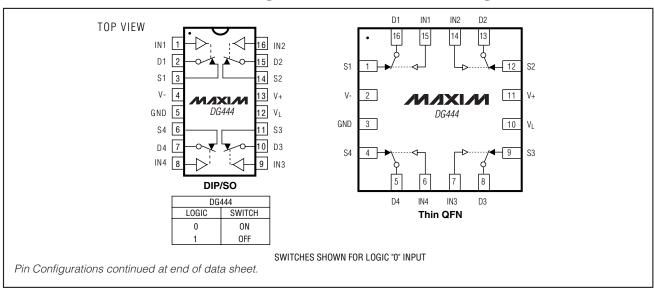
Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
DG444CJ	0°C to +70°C	16 Plastic DIP
DG444CY	0°C to +70°C	16 Narrow SO
DG444C/D	0°C to +70°C	Dice*
DG444DJ	-40°C to +85°C	16 Plastic DIP
DG444DY	-40°C to +85°C	16 Narrow SO

Ordering Information continued at end of data sheet.

*Contact factory for dice specifications.

Pin Configurations/Functional Diagrams/Truth Tables



M/IXI/N/

Maxim Integrated Products 1



ABSOLUTE MAXIMUM RATINGS

(Voltage Referenced to V-)	
V+	44V
GND	25V
V _L (GND - 0.3V)	to $(V + + 0.3V)$
Digital Inputs V _S , V _D (Note 1)(V 2V) to (V+ -	+ 2V) or 30mA
(whichev	er occurs first)
Continuous Current (any terminal)	30mA
Peak Current, S or D (pulsed at 1ms, 10% duty cycle	e max) .100mA

Continuous Power Dissipation (T _A = +70°C)	
6-Pin Narrow SO (derate 8.70mW/°C above	
16-Pin PDIP (derate 10.53mW/°C above +	70°C)842mW
16-Pin Thin QFN (derate 33.3mW/°C above	e +70°C)2667mW
Operating Temperature Ranges	
DG444C/DG445C	0°C to +70°C
DG444D, E/DG445D, E	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Note 1: Signals on S, D, or IN exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = 15V, V- = -15V, VL = 5V, GND = 0, VINH = 2.4V, VINL = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITI	ONS	MIN	TYP (Note 2)	MAX	UNITS	
SWITCH								
Analog Signal Range	Vanalog	(Note 3)		-15		+15	V	
Drain-Source	Process	V+ = 13.5V, V- = -13.5V,	T _A = +25°C		50	85	Ω	
On-Resistance	R _{DS(ON)}	$V_D = \pm 8.5 V$, $I_S = -10 \text{mA}$	TA = TMIN to TMAX			100	22	
On-Resistance Match	APparation	$V_D = \pm 10V$,	T _A = +25°C			4	0	
Between Channels (Note 4)	ΔR _{DS(ON)}	Is = -10mA	TA = TMIN to TMAX			5	Ω	
On Decistance Flatness (Note 4)	D=: .=:0.::	$V_D = \pm 5V$,	T _A = +25°C			9	Ω	
On-Resistance Flatness (Note 4)	MFLAT(ON)	$I_S = -10mA$	TA = TMIN to TMAX			15	22	
Source Leakage Current		V+ = 16.5V, V- = -16.5V,	T _A = +25°C	-0.50	+0.01	+0.50	- ^	
(Note 5)	IS(OFF)	$V_D = \pm 15.5V$, $V_S = \mp 15.5V$	TA = TMIN to TMAX	-5		+5	nA	
Drain Off-Leakage Current		V+ = 16.5V, V- = -16.5V,	T _A = +25°C	-0.50	+0.01	+0.50	nA	
(Note 5)	ID(OFF)	$V_D = \pm 15.5V$, $V_S = \mp 15.5V$	TA = TMIN to TMAX	-5		+5		
Drain On-Leakage Current	I _{D(ON)}	V+ = 16.5V, V- = -16.5V,	T _A = +25°C	-0.50 +0.08		+0.50		
(Note 5)	or I _{S(ON)}	$V_D = \pm 15.5V$, $V_S = \pm 15.5V$	TA = TMIN to TMAX	-10		+10	nA	
INPUT				I				
Input Current with Input Voltage High	linh	V _{IN} = 2.4V, all others = 0	.8V	-0.5	-0.00001	+0.5	μΑ	
Input Current with Input Voltage Low	I _{INL}	$V_{IN} = 0.8V$, all others = 2	.4V	-0.5	-0.00001	+0.5	μΑ	



Improved, Quad, SPST Analog Switches

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

 $(V+ = 15V, V- = -15V, V_L = 5V, GND = 0, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS					
SWITCH	1			±4.5 ±20.0 V -1 -0.001 +1 -5 +5 -1 -0.0001 +1 -5 +5 -1 -0.001 +1 -5 +5 -1 -0.0001 +1 -5 +5 -1 -1 -0.0001 +1 μA -5 +5 -1 -1 -0.0001 +1 μA								
Power-Supply Range	V+, V-			±4.5		±20.0	V					
Positive Supply Current	l+	All channels on or off, V+ = 16.5V, V- = -16.5V, V _{IN} = 0V	T _A = +25°C	-1	-0.001	+1	ПΔ					
rositive Supply Current	1+	or 5V	TA = TMIN to TMAX	-5		+5	μΑ					
Negative Supply Current	-	All channels on or off, V+ = 16.5V, V- = -16.5V, V _{IN} = 0V	T _A = +25°C	-1	-0.0001	+1						
Negative Supply Current	-	or 5V	$T_A = T_{MIN}$ to T_{MAX}	-5		+5	μΑ					
Logio Cupply Current	lı lı	All channels on or off, V+ = 16.5V, V- = -16.5V, V _{IN} = 0V	T _A = +25°C	-1	-0.001	+1						
Logic Supply Current	"L	or 5V	$T_A = T_{MIN}$ to T_{MAX}	-5		+5	μΑ					
0	lovin	All channels on or off, V+ = 16.5V, V- = -16.5V, V _{IN} = 0V	T _A = +25°C	-1	-0.0001	+1						
Ground Current	IGND	or 5V	TA = TMIN to TMAX	-5		+5	μΑ					
INPUT	'											
Turn-On Time	toN	$V_S = \pm 10V$, Figure 2	T _A = +25°C		150	250	ns					
Turn Off Times	40	DG444, V _S = ±10V, Figure 2	T _A = +25°C		90	120	ns					
Turn-Off Time	toff	DG445, $V_S = \pm 10V$, Figure 2	T _A = +25°C		110	170	ns					
Charge Injection (Note 3)	Q	$C_L = 1nF$, $V_{GEN} = 0$, $R_{GEN} = 0\Omega$, Figure 3	T _A = +25°C		5	10	рС					
Off-Isolation Rejection Ratio (Note 6)	OIRR	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 4	T _A = +25°C		60		dB					
Crosstalk (Note 7)		R_L -50 Ω , C_L = 5pF, f = 1MHz, Figure 5	TA = +25°C		100		dB					
Source Off-Capacitance	C _{S(OFF)}	f = 1MHz, Figure 6	T _A = +25°C		4		рF					
Drain Off-Capacitance	C _D (OFF)	f = 1MHz, Figure 6	T _A = +25°C		4		pF					
Source On-Capacitance	C _{S(ON)}	f = 1MHz, Figure 7	T _A = +25°C		16		рF					
Drain On-Capacitance	C _{D(ON)}	f = 1MHz, Figure 7	T _A = +25°C		16		pF					



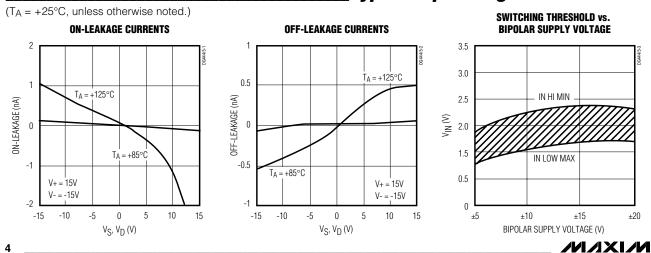
ELECTRICAL CHARACTERISTICS—Single Supply

(V+ = 12V, V- = 0, VL = 5V, GND = 0, VINH = 2.4V, VINL = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITI	ONS	MIN	TYP (Note 2)	MAX	UNITS	
SWITCH								
Analog Signal Range	Vanalog	(Note 3)		0		12	V	
Drain-Source	Б	V+ = 10.8V; V _L = 5.25V;	T _A = +25°C		100	160		
On-Resistance	R _{DS} (ON)	$V_D = 3V, 8V; I_S = -10mA$	$T_A = T_{MIN}$ to T_{MAX}			200	Ω	
SUPPLY								
Power-Supply Range	V+, V-			10.8		24.0	V	
Power-Supply Current	I+	All channels on or off,	T _A = +25°C	-1	+0.001	+1	μΑ	
	1+	VIN = 0V or 5V	TA = TMIN to TMAX	-5		+5	μΑ	
Negative Supply Current	I-	All channels on or off,	T _A = +25°C	-1	-0.0001	+1	μА	
negative Supply Current	1-	$V_{IN} = 0V \text{ or } 5V$	$T_A = T_{MIN}$ to T_{MAX}	-5		+5		
Logic Supply Current	IL	All channels on or off,	T _A = +25°C	-1	+0.001	+1	μΑ	
Logic Supply Current	'L	$V_{IN} = 0V \text{ or } 5V$	$T_A = T_{MIN}$ to T_{MAX}	-5		+5	μΑ	
Ground Current	IGND	All channels on or off, $TA = +25$ °C		-1	-0.0001	+1	μА	
Ground Current	IGND	$V_{IN} = 0V \text{ or } 5V$	$T_A = T_{MIN}$ to T_{MAX}	-5 +5		+5	μA	
DYNAMIC								
Turn-On Time	ton	V _S = 8V, Figure 2	T _A = +25°C		300	400	ns	
Turn-Off Time	toff	V _S = 8V, Figure 2	T _A = +25°C		60	200	ns	
Charge Injection (Note 3)	Q	$C_L = 1nF$, $V_{GEN} = 0$, $R_{GEN} = 0\Omega$, Figure 3	T _A = +25°C		5	10	рС	

- **Note 2:** Typical values are for **design aid only**, are not guaranteed, and are not subject to production testing. The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.
- Note 3: Guaranteed by design.
- **Note 4:** On-resistance match between channels and flatness are guaranteed only with bipolar-supply operation. Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured at the extremes of the specified analog signal range.
- Note 5: Leakage parameters IS(OFF), ID(OFF), ID(ON), and IS(ON) are 100% tested at the maximum rated hot temperature and guaranteed at +25°C.
- Note 6: Off-Isolation Rejection Ratio = 20log (VD/Vs), VD = output, Vs = input to off switch.
- Note 7: Between any two switches.

Typical Operating Characteristics

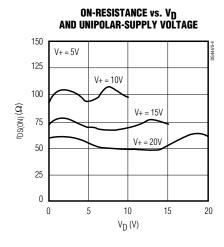


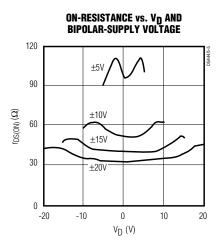


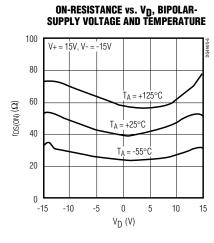
Improved, Quad, SPST Analog Switches

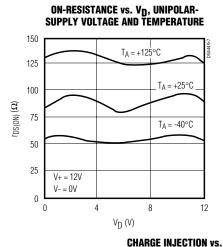
Typical Operating Characteristics

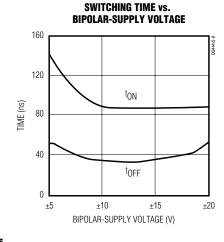
 $(T_A = +25^{\circ}C, unless otherwise noted.)$

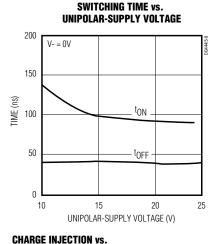


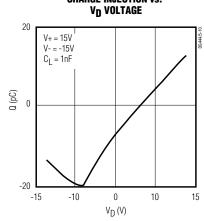


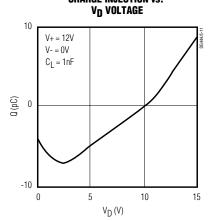












/U/IXI/U



Pin Description

PI	N	NAME	FUNCTION
DIP/SO	THIN QFN	NAME	FUNCTION
1, 16, 9, 8	15, 14, 7, 6	IN1-IN4	Logic Control Inputs
2, 15, 10, 7	16, 13, 8, 5	D1-D4	Drain Outputs
3, 14, 11, 6	1, 12, 9 4	S1–S4	Source Outputs
4	2	V-	Negative-Supply Voltage Input
5	3	GND	Ground
12	10	VL	Logic-Supply Voltage Input
13	11	V+	Positive-Supply- Voltage Input—Connected to Substrate
	EP	PAD	Exposed Pad Connect Pad to V+

Applications Information

General Operation

- Switches are open when power is off.
- IN, D, and S should not exceed V+ or V-, even with the power off.
- Switch leakage is from each analog switch terminal to V+ or V-, not to other switch terminals.

Operation with Supply Voltages Other than ±15V

Using supply voltages other than ±15V will reduce the analog signal range. The DG444/DG445 switches oper-

ate with $\pm 4.5 \text{V}$ to $\pm 20 \text{V}$ bipolar supplies or with a +10 V to +30 V single supply; connect V- to 0V when operating with a single supply. Also, all device types can operate with unbalanced supplies such as +24 V and -5 V. V_L must be connected to +5 V to be TTL compatible, or to V+ for CMOS-logic level inputs. The *Typical Operating Characteristics* graphs show typical on-resistance with $\pm 20 \text{V}$, $\pm 15 \text{V}$, $\pm 10 \text{V}$, and $\pm 5 \text{V}$ supplies. (Switching times increase by a factor of two or more for operation at $\pm 5 \text{V}$.)

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, followed by VL, V-, and logic inputs. If power-supply sequencing is not possible, add two small, external signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to 1V below V+ and 1V above V-, but low switch resistance and low leakage characteristics are unaffected. Device operation is unchanged, and the difference between V+ and V-should not exceed +44V.

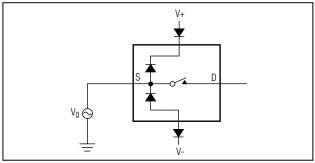


Figure 1. Overvoltage Protection Using External Blocking Diodes

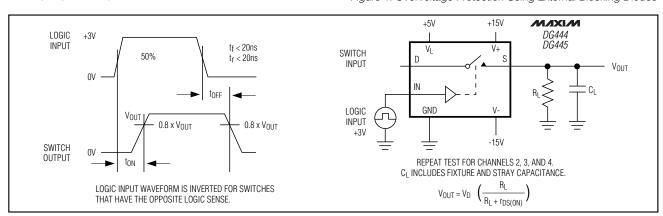


Figure 2. Switching Time

__ /N/XI/N



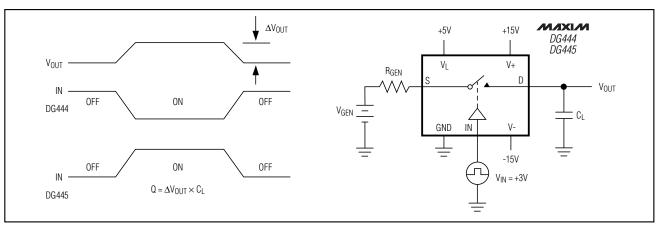


Figure 3. Charge Injection

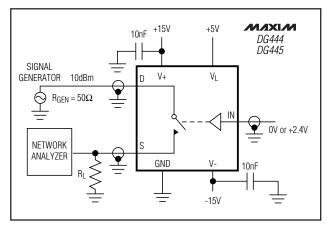


Figure 4. Off-Isolation Rejection Ratio

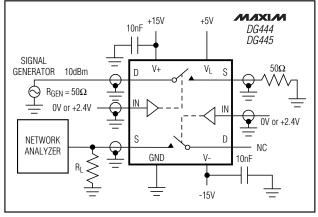


Figure 5. Crosstalk

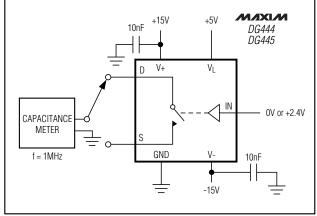


Figure 6. Source/Drain Off-Capacitance

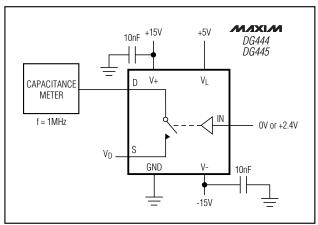
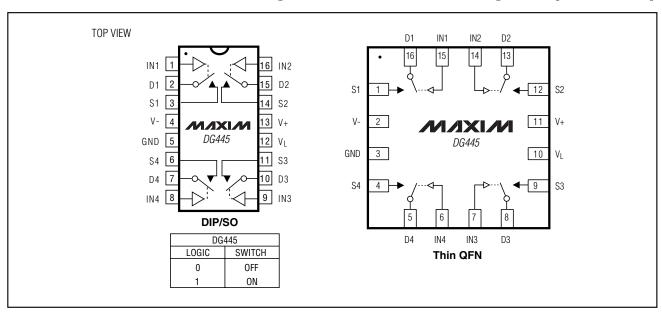


Figure 7. Source/Drain On-Capacitance





Pin Configurations/Functional Diagrams (continued)



Ordering Information (continued)

PART	TEMP RANGE	PIN-PACKAGE
DG444ETE	-40°C to +85°C	16 Thin QFN (5mm x 5mm)
DG445CJ	0°C to +70°C	16 Plastic DIP
DG445CY	0°C to +70°C	16 Narrow SO
DG445C/D	0°C to +70°C	Dice*
DG445DJ	-40°C to +85°C	16 Plastic DIP
DG445DY	-40°C to +85°C	16 Narrow SO
DG445ETE	-40°C to +85°C	16 Thin QFN (5mm x 5mm)

^{*}Contact factory for dice specifications.

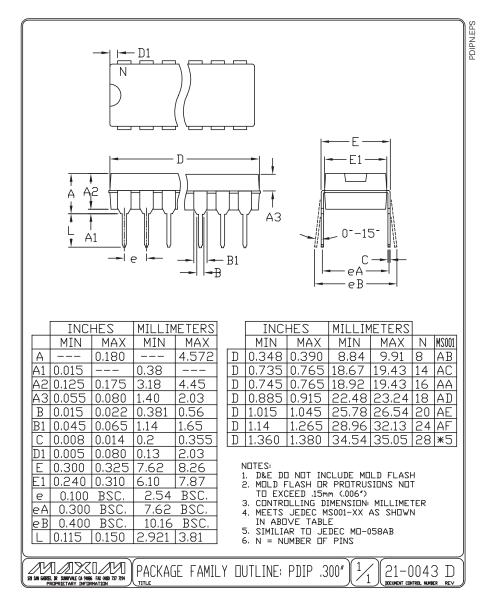
8 ______ **/\!X\!/**



Improved, Quad, SPST Analog Switches

_Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)

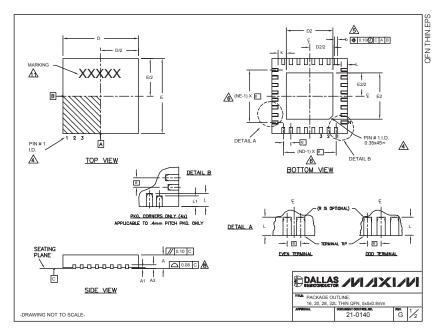




Improved, Quad, SPST Analog Switches

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



			C	OMM	ON DI	MENS	IONS								EXF	POSED	PAD	VARIA	TIONS	;		
PKG.	- 1	6L 5x	5	2	20L 5:	ĸ5	2	8L 5>	5	3	32L 5x5		PKG		.		D2		E2			DOWN
SYMBOL	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		CODES	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	±0.15	ALLOWE
A	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80	0.70	0.75	0.80		T1655-1	3.00	3.10	3.20	3.00	3.10	3.20	**	NO
A1	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05	0	0.02	0.05		T1655-2	3.00	3.10	3.20	3.00	3.10	3.20	**	YES
A3	0	20 RF	F	0	20 RF	F	0:	20 RF	F	0	20 RF	F		T1655N-1	3.00	3.10	3.20	3.00	3.10	3.20	**	NO
b	0.25	0.30	0.35	0.25	0.30	0.35	0.20	0.25	0.30	0.20	0.25	0.30		T2055-2	3.00	3.10	3.20	3.00	3.10	3.20	**	NO
D	4 90	5.00	5 10	_	5.00	5 10	4 90	5.00		4 90	5.00	5 10		T2055-3	3.00	3.10	3.20	3.00	3.10	3.20	**	YES
Е	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10	4.90	5.00	5.10		T2055-4	3.00	3.10	3.20	3.00	3.10	3.20	**	NO
e	_	80 BS	_	_	.65 B		_	50 BS	_	_	.50 BS	_		T2055-5	3.15	3.25	3.35	3.15	3.25	3.35	0.40	Y
k	0.25	-	-	0.25	-	T -	0.25	-	-	0.25	-	Ι.		T2855-1	3.15	3.25	3.35	3.15	3.25	3.35	**	NO
L	0.20	0.40	0.50	0	0.55	0.65	0.45	0.55	0.65	0.20	0.40	0.50		T2855-2	2.60	2.70	2.80	2.60	2.70	2.80	**	NO
11	-	-	-	-	-	-	2.10	-	-	-	-	-		T2855-3	3.15	3.25	3.35	3.15	3.25	3.35	**	YES
N	Ĥ	16		H	20		H	28		H	32			T2855-4	2.60	2.70	2.80	2.60	2.70	2.80	**	YES
ND.	-	4			5			7		8				T2855-5	2.60	2.70	2.80	2.60	2.70	2.80	**	NO
NF	-	4			5			7		8			T2855-6	3.15	3.25	3.35	3.15	3.25	3.35	**	NO	
JEDEC	_	WHHE		-	WHH	2	V	VHHD	-1	V	WHHD-2			T2855-7 T2855-8	2.60	2.70 3.25	2.80	2.60	2.70	2.80 3.35	**	YES
JEDEC	_			_				******	•	<u> </u>		_		T2855N-1	3.15	3.25	3.35	3.15	3.25	3.35	0.40	N
OTES:														T3255-2	3.00	3.10	3.20	3.00	3.10	3.20	**	NO.
1. DIMENS	SIONIN	G & T0	DLERA	NCING	CONF	ORM 1	O ASM	IE Y14	5M-19	94.				T3255-3	3.00	3.10	3.20	3.00	3.10	3.20	**	YES
2. ALL DI	MENSI	A SAC	RE IN N	VILLIM	ETERS	. ANG	ES AR	E IN D	EGRE	ES.				T3255-4	3.00	3.10	3 20	3 00	3.10	3 20	**	NO
3. N IS TH	E TO	AL NU	MBER	OF TE	RMINA	LS.								T3255N-1	3.00	3.10	3.20	3.00	3.10	3.20	**	NO
THE TE CONFO OPTION IDENTINATION FROM	ORM TO NAL, B IFIER I SION I	UT MU MAY BE APPLI	95-1 S ST BE EITHE ES TO	SPP-01 LOCA ER A M	2. DE TED W IOLD C	TAILS (ITHIN T IR MAR	F TER HE ZO KED FI	MINAL NE INE EATUR	#1 IDE OICATE E.	NTIFII D. THI	ER ARE	Ξ ∕IINAL ≠	n ANE	0.30 mm				**	SEE COI	MMON E	DIMENSIC	INS TABLE
<u>∕6</u> ND ANI	D NE F	EFER	то тні	E NUM	BER C	F TER	MINALS	ON E	ACH D	AND I	SIDE	RESPE	ELY.									
7. DEPOR	ULATI	ON IS I	POSSIE	BLE IN	A SYN	METR	CAL FA	SHIO	۷.													
∧ COPLA	NARIT	Y APPI	LIES TO	O THE	EXPO:	SED HE	AT SIN	IK SLU	G AS I	NELL A	AS THE	TERM	S.									
 DRAWI T2855- 				JEDE	C MO2	20, EX	CEPT E	XPOS	ED PAI	D DIME	NSION	FOR '	i-1,			1	DAL	.LA	ş 🕢		<u>/I3</u>	<u> </u>
10. WARPA	GE SH	IALL N	OT EXC	CEED	0.10 mi	m.										I'D	BERNICO	REDUCTO	R #	WF 10.	7 A B	~12
MARKIN	NG IS I	OR PA	CKAG	E ORIE	NTAT	ION RE	FEREN	ICE ON	ILY.							TITLE	PACK	AGE O	JTLINE,			
																		. 28. 32				

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